NPN Epitaxial Planar Silicon Transistor



2SD2028

# Low-Frequency Power Amplifier Applications

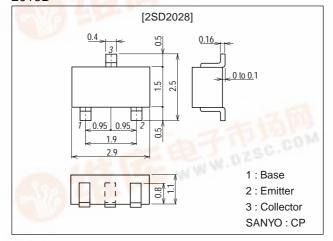
#### **Features**

- · With Zener diode (11±3V) between collector and base.
- · Large current capacity.
- · Low collector-to-emitter saturation voltage.
- · Ultrasmall-sized package permitting the 2SD2028-applied sets to be made small and slim.

### **Package Dimensions**

unit:mm

2018B



### **Specifications**

### Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CBO</sub>	With Zener diode (11±3V)	8	V
Collector-to-Emitter Voltage	VCEO	With Zener diode (11±3V)	8	V
Emitter-to-Base Voltage	V <sub>EBO</sub>	110	5	V
Collector Current	IC	and T	0.7	Α
Collector Current (Pulse)	I <sub>CP</sub>	- s.b. (1000)	1.5	А
Collector Dissipation	PC	AND A PART PORT	200	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg	CHO FRINGS	-55 to +150	°C

## Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> =6V, I <sub>E</sub> =0			100	nA
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =4V, I <sub>C</sub> =0		1	100	nA
DC Current Gain	h <sub>FE</sub> 1	$V_{CE}=2V$ , $I_{C}=50mA$	200*	. —	900*	1111
Do Current Gain	h <sub>FE</sub> 2	V <sub>CE</sub> =2V, I <sub>C</sub> =500mA	100			:01
Gain-Bandwidth Product	fT	V <sub>CE</sub> =2V, I <sub>C</sub> =50mA		200	19.0	MHz
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =5V, f=1MHz	AL AL	12		pF

 $\mbox{\ensuremath{^{*}}}$  : The 2SD2028 is classified by 50mA  $\mbox{\ensuremath{h_{FE}}}$  as follows :

200 6 400 300 7 600 450 8 900

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- (Note) Marking : LT h<sub>FE</sub> rank : 6, 7, 8
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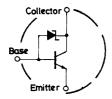
SANYO Electric Co.,Ltd. Semiconductor Bussiness Headquaters

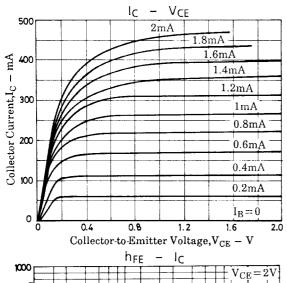
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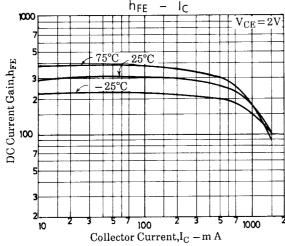
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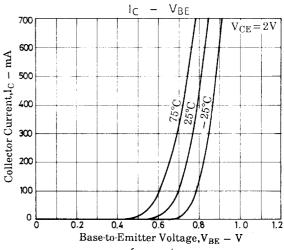
Parameter	Symbol	Conditions	Ratings			Unit
	Symbol		min	typ	max	Offic
Collector-to-Emitter Saturation Voltage	VCE(sat)	I <sub>C</sub> =100mA, I <sub>B</sub> =10mA		50	120	mV
Base-to-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =100mA, I <sub>B</sub> =10mA		0.8	1.2	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I <sub>C</sub> =100μA, I <sub>E</sub> =0	8	11	14	V
Collector-to-Emitter Breakdown Voltage	V <sub>(BR)</sub> CEO	I <sub>C</sub> =100μA, R <sub>BE</sub> =∞	8	11	14	V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I <sub>E</sub> =10μA, I <sub>C</sub> =0	5			V

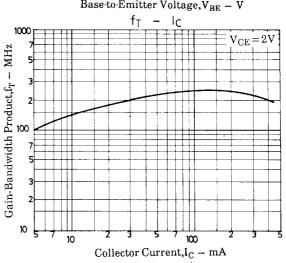
#### **Electrical Connection**



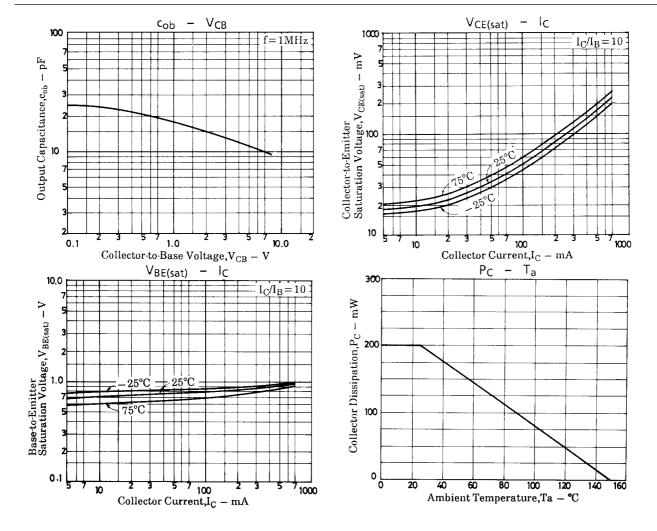








### 2SD2028



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